VS-GB75LP120N

Vishay Semiconductors

Molding Type Module IGBT, Chopper in 1 Package, 1200 V, 75 A



www.vishay.com

PRODUCT SUMMARY	
V _{CES}	1200 V
I _C at T _C = 80 °C	75 A
V _{CE(on)} (typical)	1.82 V

8 kHz to 30 kHz

INT-A-PAK

Half bridge

at I_C = 75 A, 25 °C

Speed Package

Circuit

FEATURES

• High short circuit capability, self limiting to $6 \times I_C$

Maximum junction temperature 150 °C

- 10 µs short circuit capability
 - ability
- V_{CE(on)} with positive temperature coefficient
- Low inductance case
- · Fast and soft reverse recovery anti-parallel FWD
- Isolated copper baseplate using DCB (Direct Copper Bonding) technology
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- AC inverter drives
- Switching mode power supplies
- Electronic welders

DESCRIPTION

Vishay's IGBT power module provides ultra low conduction loss as well as short circuit ruggedness. It is designed for applications such as general inverters and UPS.

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Collector to emitter voltage	V _{CES}		1200	V
Gate to emitter voltage	V _{GES}		± 20	v
Collector current	1	T _C = 25 °C	170	
Collector current	I _C	T _C = 80 °C	75	
Pulsed collector current	I _{CM} ⁽¹⁾	t _p = 1 ms	150	А
Diode continuous forward current	I _F		75	
Diode maximum forward current	I _{FM}		150	
Maximum power dissipation	PD	$T_{\rm J} = 150 \ ^{\circ}{\rm C}$	658	W
Short circuit withstand time	t _{SC}	T _J = 125 °C	10	μs
RMS isolation voltage	VISOL	f = 50 Hz, t = 1 min	2500	V
l ² t-value, diode	l ² t	V_{R} = 0 V, t = 10 ms, T_{J} = 125 °C	1190	A ² s
Operating junction temperature range	TJ		-40 to +150	°C

Note

⁽¹⁾ Repetitive rating: pulse width limited by maximum junction temperature.

IGBT ELECTRICAL SPECIFICATIONS ($T_c = 25 \degree C$ unless otherwise noted)						
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS M		TYP.	MAX.	UNITS
Collector to emitter breakdown voltage	V _{(BR)CES}	$T_J = 25 \ ^{\circ}C$	1200	-	-	
Collector to emitter voltage	V _{CE(on)}	V_{GE} = 15 V, I_{C} = 75 A, T_{J} = 25 °C	-	1.82	-	v
Collector to enlitter voltage		$V_{GE} = 15 \text{ V}, \text{ I}_{C} = 75 \text{ A}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	2.05	-	v
Gate to emitter threshold voltage	V _{GE(th)}	V_{CE} = V_{GE} , I_C = 3.0 mA, T_J = 25 °C	5.0	6.2	7.0	
Collector cut-off current	I _{CES}	$V_{CE} = V_{CES}, V_{GE} = 0 \text{ V}, \text{ T}_{J} = 25 ^{\circ}\text{C}$	-	-	1.0	mA
Gate to emitter leakage current	I _{GES}	$V_{GE} = V_{GES}, V_{CE} = 0 \text{ V}, \text{ T}_{J} = 25 ^{\circ}\text{C}$	-	-	400	nA

Revision: 10-Jun-15

1

Document Number: 94825

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



COMPLIANT





Vishay Semiconductors

SWITCHING CHARACTERISTICS	5					
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-on delay time	t _{d(on)}		-	140	-	
Rise time	t _r		-	37	-	ns
Turn-off delay time	t _{d(off)}	$V_{CC} = 600 \text{ V}, \text{ I}_{C} = 75 \text{ A}, \text{ R}_{g} = 4.7 \Omega,$	-	370	-	
Fall time	t _f	$V_{GE} = \pm 15 \text{ V}, \text{ T}_{J} = 25 \text{ °C}$	-	55	-	
Turn-on switching loss	E _{on}		-	7.2	-	
Turn-off switching loss	E _{off}		-	4.5	-	mJ
Turn-on delay time	t _{d(on)}		-	150	-	ns
Rise time	t _r		-	40	-	
Turn-off delay time	t _{d(off)}	$V_{CC} = 600 \text{ V}, \text{ I}_{C} = 75 \text{ A}, \text{ R}_{g} = 4.7 \Omega,$	-	400	-	
Fall time	t _f	V _{GE} = ± 15 V, T _J = 125 °C	-	64	-	
Turn-on switching loss	E _{on}		-	9.0	-	
Turn-off switching loss	E _{off}		-	7.4	-	mJ
Input capacitance	Cies		-	5.52	-	
Output capacitance	C _{oes}	V _{GE} = 0 V, V _{CE} = 25 V, f = 1.0 MHz	-	0.40	-	nF
Reverse transfer capacitance	C _{res}		-	0.26	-	
SC data	I _{SC}	$\label{eq:tsc} \begin{array}{l} t_{sc} \leq 10 \ \mu s, \ V_{GE} = 15 \ V, \ T_J = 125 \ ^{\circ}C, \\ V_{CC} = 900 \ V, \ V_{CEM} \leq 1200 \ V \end{array}$	-	420	-	А
Internal gate resistance	R _{gint}		-	3	-	Ω
Stray inductance	L _{CE}		-	-	30	nH
Module lead resistance, terminal to chip	R _{CC'+EE'}	T _C = 25 °C	-	0.75	-	mΩ

DIODE ELECTRICAL SPECIFICATIONS (T _C = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS	
Diode forward voltage	V _F I	I _F = 75 A	T _J = 25 °C	-	2.05	-	v	
Didde forward voltage			T _J = 125 °C	-	2.25	-		
Diada rayarga ragayany aharga	t _{rr}		T _J = 25 °C	-	100	-	μC	
Diode reverse recovery charge			T _J = 125 °C	-	125	-	μΟ	
Diode peak reverse recovery current	I _{rr}		I _F = 75 A, V _R = 600 V, dI _F /dt = -2000 A/μs,	T _J = 25 °C	-	80	-	А
Didde peak reverse recovery current		$V_{GF} = -15 V$	T _J = 125 °C	-	100	-	A	
Diada rayarga ragayany anargy		32	VGE - 10 V	T _J = 25 °C	-	3.0	-	ml
Diode reverse recovery energy	E _{rec}		T _J = 125 °C	-	6.0	-	mJ	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Operating junction temperature range	TJ		-40	-	150	0
Storage temperature range	T _{STG}		-40	-	125	C
Junction to case IGBT (per 1/2 module)	_		-	-	0.19	
Diode (per 1/2 module)	R _{thJC}		-	-	0.48	K/W
Case to sink	R _{thCS}	Conductive grease applied	-	0.05	-	
Mounting torque		Power terminal screw: M5	2.5 to 5.0		Nm	
Mounting torque		Mounting screw: M6	3.0 to 6.0		INITI	
Weight of module				150		g

Revision: 10-Jun-15

Document Number: 94825



Vishay Semiconductors

Eor

40

0.4

20

25

30

35

50

Eoff

60

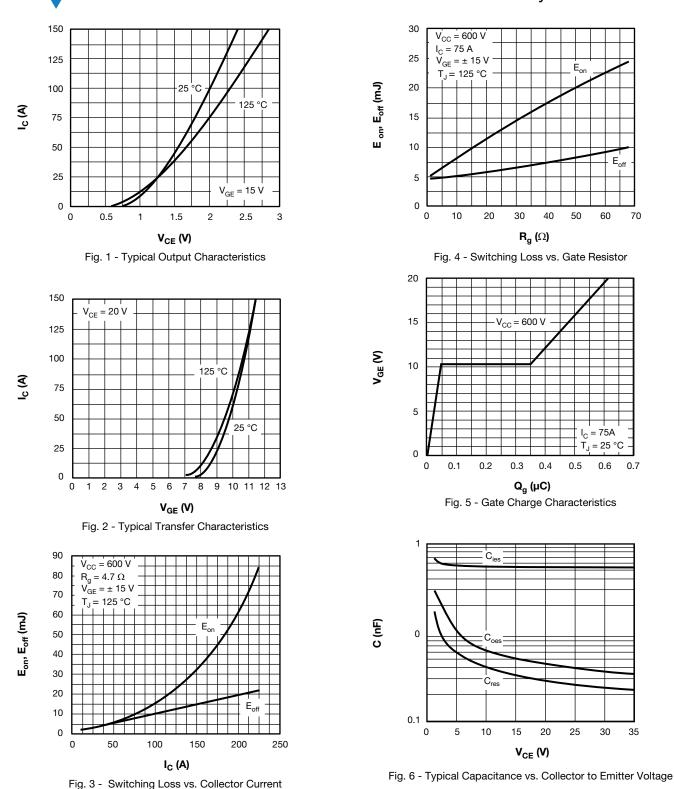
I_C = 75A = 25 °C

0.6

0.5

0.7

70



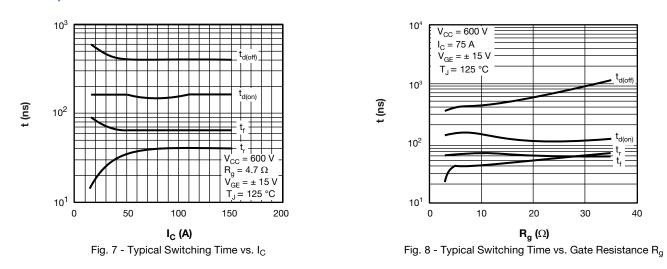
ISHAY

www.vishay.com

Revision: 10-Jun-15 Document Number: 94825 3 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

VS-GB75LP120N

Vishay Semiconductors



ISHAY

www.vishay.com

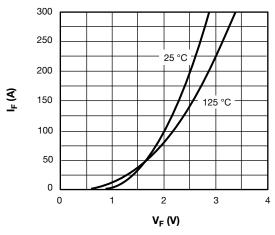
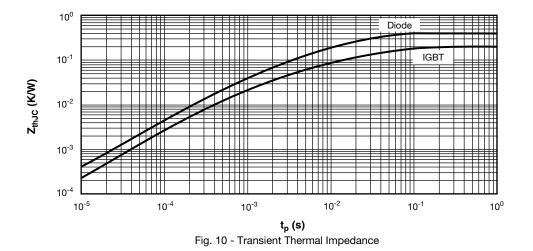


Fig. 9 - Diode Typical Forward Characteristics



 Revision: 10-Jun-15
 4
 Document Number: 94825

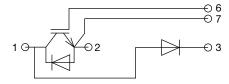
 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesAsia@vishay.com, DiodesEurope@vishay.com

 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay Semiconductors

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95524			

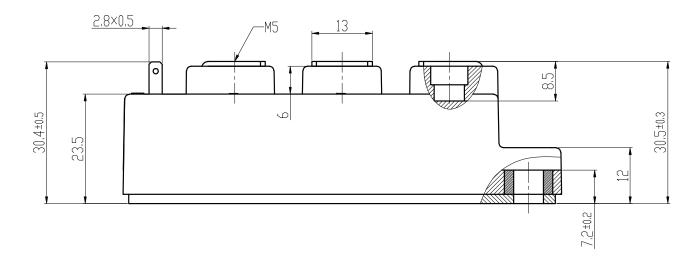
Outline Dimensions

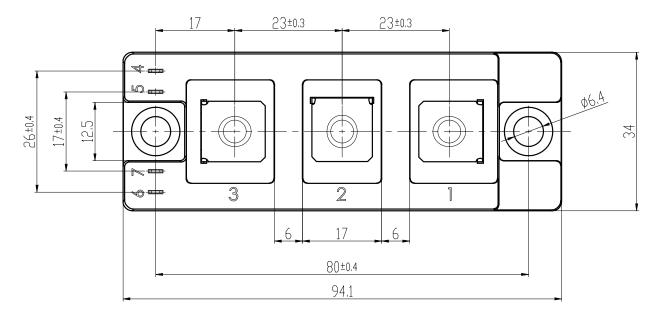


Vishay Semiconductors

INT-A-PAK

DIMENSIONS in millimeters (inches)







Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.